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MOS FIELD EFFECT TRANSISTOR 2SJ461

P-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR HIGH SPEED SWITCHING

DESCRIPTION

The 2SJ461 is a switching device which can be driven directly by a 2.5 V power source.

The MOS FET has excellent switching characteristics and is suitable for use as a high-speed switching device in digital circuits.

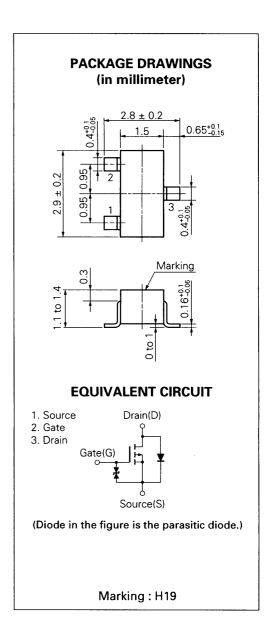
FEATURES

- Can be driven by a 2.5 V power source.
- Not necessary to consider driving current because of its high input impedance.
- Possible to reduce the number of parts by omitting the bias resistor.

ABSOLUTE MAXIMUM RATINGS (TA = +25 °C)

Drain to Source Voltage	Voss	-50	V
Gate to Source Voltage	Vgss	+ 7.0	V
Drain Current (DC)	ID(DC)	∓0.1	Α
Drain Current (pulse)	D(pulse)	∓0.2 *	Α
Total Power Dissipation	Рт	200	mW
Channel Temperature	Тсн	150	°C
Storage Temperature	Tstg	-55 to +150	°C

^{*}PW \leq 10 ms, Duty cycle \leq 1 %



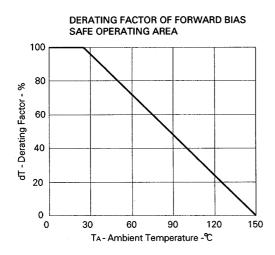
The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device is actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

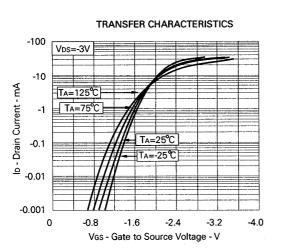


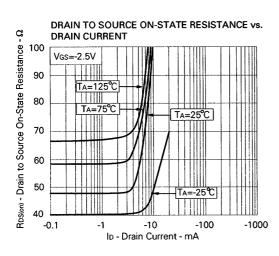
ELECTRICAL CHARACTERISTICS (TA = +25 °C)

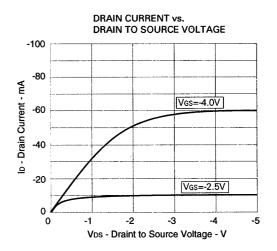
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Drain Cut-off Current	IDSS			-1.0	μΑ	VDS = -50 V, VGS = 0	
Gate Leakage Current	Igss			∓3.0	μΑ	Vgs = + 7.0 V, Vps = 0	
Gate Cut-off Voltage	VGS(off)	-0.7	-0.9	-1.3	V	$V_{DS} = -3.0 \text{ V, ID} = -1.0 \ \mu\text{A}$	
Forward Transfer Admittance	yfs	12			mS	VDS = -3.0 V, ID = -10 mA	
Drain to Source On-State Resistance	RDS(on)1		46	100	Ω	$V_{GS} = -2.5 \text{ V, ID} = -3 \text{ mA}$	
Drain to Source On-State Resistance	RDS(on)2		31	50	Ω	Vgs = -4.0 V, lp = -10 mA	
Input Capacitance	Ciss		6		рF	V _{DS} = -3.0 V, V _{GS} = 0 f = 1.0 MHz	
Output Capacitance	Coss		9		pF		
Reverse Transfer Capacitance	Crss		1.6		pF		
Turn-On Delay Time	td(on)		32		ns	$V_{DD} = -3.0 \text{ V, ID} = -20 \text{ mA}$ $V_{GS(on)} = -3.0 \text{ V, Rg} = 10 \Omega$	
Rise Time	tr		270		ns		
Turn-Off Delay Time	td(off)		45		ns		
Fall Time	tr		130		ns	RL = 200 Ω	

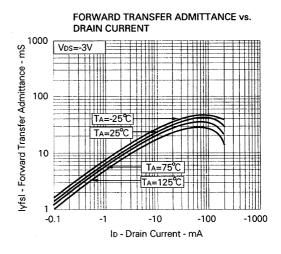
TYPICAL CHARACTERISTICS (TA = 25 °C)

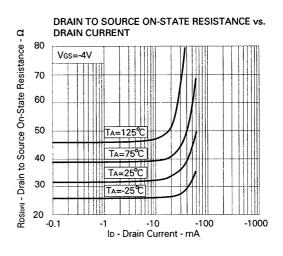


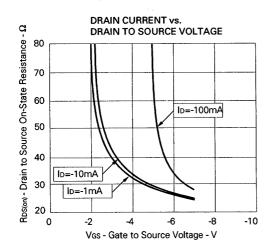


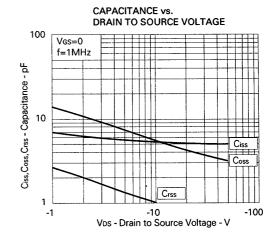


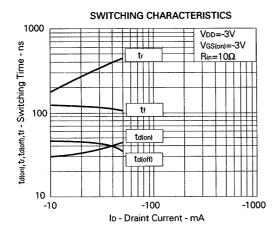


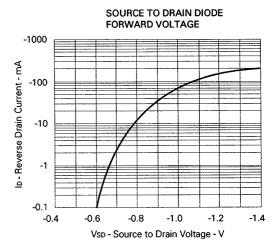














REFERENCE

Document Name	Document No.	
NEC semiconductor device reliability/quality control system	TEI-1202	
Quality grade on NEC semiconductor devices	IEI-1209	
Semiconductor device mounting technology manual	C10535EJ7V0IF00	
Guide to quality assurance for semiconductor devices	MEI-1202	
Semiconductor selection guide	X10679EJAV0SG00	

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Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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Anti-radioactive design is not implemented in this product.

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